# International **TOR** Rectifier

### AUTOMOTIVE GRADE

# AUIRLL024N

### HEXFET<sup>®</sup> Power MOSFET

#### Features

- Advanced Planar Technology
- Low On-Resistance
- Dynamic dV/dT Rating
- 150°C Operating Temperature
- Fast Switching
- Fully Avalanche Rated
- Repetitive Avalanche Allowed up to Tjmax
- Lead-Free, RoHS Compliant
- Automotive Qualified \*

#### Description

Specifically designed for Automotive applications, this Cellular design of HEXFET® Power MOSFETs utilizes the latest processing techniques to achieve low onresistance per silicon area. This benefit combined with the fast switching speed and ruggedized device design that HEXFET power MOSFETs are well known for, provides the designer with an extremely efficient and reliable device for use in Automotive and a wide variety of other applications.

D TIST S G
SOT-223 AUIRLL024N

G	D	S
Gate	Drain	Source

### **Absolute Maximum Ratings**

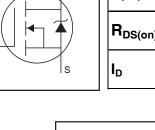
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only; and functional operation of the device at these or any other condition beyond those indicated in the specifications is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability. The thermal resistance and power dissipation ratings are measured under board mounted and still air conditions. Ambient temperature ( $T_A$ ) is 25°C, unless otherwise specified.

	Parameter	Max.	Units
I <sub>D</sub> @ T <sub>A</sub> = 25°C	Continuous Drain Current, V <sub>GS</sub> @ 10V <sup>®</sup>	4.4	
I <sub>D</sub> @ T <sub>A</sub> = 25°C	Continuous Drain Current, V <sub>GS</sub> @ 10V <sup>®</sup>	3.1	•
I <sub>D</sub> @ T <sub>A</sub> = 70°C	Continuous Drain Current, V <sub>GS</sub> @ 10V <sup>⑤</sup>	2.5	A
IDM	Pulsed Drain Current ①	12	
P <sub>D</sub> @T <sub>A</sub> = 25°C	Power Dissipation (PCB Mount)®	2.1	W
P <sub>D</sub> @T <sub>A</sub> = 25°C	Power Dissipation (PCB Mount)	1.0	W
	Linear Derating Factor (PCB Mount)	8.3	W/°C
V <sub>GS</sub>	Gate-to-Source Voltage	± 16	V
E <sub>AS</sub>	Single Pulse Avalanche Energy <sup>②</sup>	120	mJ
I <sub>AR</sub>	Avalanche Current ①	3.1	A
E <sub>AR</sub>	Repetitive Avalanche Energy <sup>①⑤</sup>	0.1	mJ
dv/dt	Peak Diode Recovery dv/dt <sup>③</sup>	5.0	V/ns
ТJ	Operating Junction and	-55 to + 150	°C
T <sub>STG</sub>	Storage Temperature Range		

#### Thermal Resistance

	Parameter	Тур.	Max.	Units
R <sub>0JA</sub>	Junction-to-Ambient (PCB mount, steady state) <sup>⑤</sup>	90	120	°C/W
R <sub>0JA</sub>	Junction-to-Ambient (PCB mount, steady state)®	50	60	0/11

HEXFET<sup>®</sup> is a registered trademark of International Rectifier. \*Qualification standards can be found at http://www.irf.com/



V <sub>(BR)DSS</sub>	55V	
R <sub>DS(on)</sub>	max.	<b>0.065</b> Ω
I <sub>D</sub>		3.1A

	Parameter	Min.	Тур.	Max.	Units	Conditions
V <sub>(BR)DSS</sub>	Drain-to-Source Breakdown Voltage	55			V	$V_{GS} = 0V, I_{D} = 250 \mu A$
$\Delta V_{(BR)DSS} / \Delta T_J$	Breakdown Voltage Temp. Coefficient		0.048		V/°C	Reference to 25°C, $I_D = 1mA$
				0.065		V <sub>GS</sub> = 10V, I <sub>D</sub> = 3.1A ④
R <sub>DS(on)</sub>	Static Drain-to-Source On-Resistance			0.080	Ω	$V_{GS} = 5.0V, I_{D} = 2.5A$ (4)
				0.100		V <sub>GS</sub> = 4.0V, I <sub>D</sub> = 1.6A ④
V <sub>GS(th)</sub>	Gate Threshold Voltage	1.0		2.0	V	$V_{DS} = V_{GS}, I_D = 250 \mu A$
gfs	Forward Transconductance	3.3			S	V <sub>DS</sub> = 25V, I <sub>D</sub> = 1.9A
I <sub>DSS</sub>	Drain-to-Source Leakage Current			25	μA	$V_{DS} = 55V, V_{GS} = 0V$
				250	μΑ	$V_{DS} = 44V, V_{GS} = 0V, T_{J} = 125^{\circ}C$
I <sub>GSS</sub>	Gate-to-Source Forward Leakage			100	-	V <sub>GS</sub> = 16V
	Gate-to-Source Reverse Leakage			-100	nA	V <sub>GS</sub> = -16V

### Static Electrical Characteristics @ $T_J = 25^{\circ}C$ (unless otherwise specified)

### Dynamic Electrical Characteristics @ $T_J = 25^{\circ}C$ (unless otherwise specified)

•	•	•			-	•
Q <sub>g</sub>	Total Gate Charge		10.4	15.6		I <sub>D</sub> = 1.9A
Q <sub>gs</sub>	Gate-to-Source Charge		1.5	2.3	nC	$V_{DS} = 44V$
Q <sub>gd</sub>	Gate-to-Drain ("Miller") Charge		5.5	8.3		$V_{GS}$ = 5.0V, See Fig 6 and 13 $\circledast$
t <sub>d(on)</sub>	Turn-On Delay Time		7.4			$V_{DD} = 28V$
t <sub>r</sub>	Rise Time		21			I <sub>D</sub> = 1.9A
t <sub>d(off)</sub>	Turn-Off Delay Time		18		ns	$R_{G} = 24 \Omega$
t <sub>f</sub>	Fall Time		25			$R_D = 15 \Omega$ , See Fig. 10 ④
C <sub>iss</sub>	Input Capacitance		510			$V_{GS} = 0V$
C <sub>oss</sub>	Output Capacitance		140		pF	$V_{DS} = 25V$
C <sub>rss</sub>	Reverse Transfer Capacitance		58			f = 1.0MHz,see Fig.5

#### **Diode Characteristics**

	Parameter	Min.	Тур.	Max.	Units	Conditions
۱ <sub>S</sub>	Continuous Source Current			3.1		MOSFET symbol
	(Body Diode)	-	А	showing the		
I <sub>SM</sub>	Pulsed Source Current			12		integral reverse <sub>G</sub>
	(Body Diode) ①			12		p-n junction diode.
V <sub>SD</sub>	Diode Forward Voltage			1.0	V	T <sub>J</sub> = 25°C, I <sub>S</sub> = 1.9A, V <sub>GS</sub> = 0V ④
t <sub>rr</sub>	Reverse Recovery Time		39	58	ns	T <sub>J</sub> = 25°C, I <sub>F</sub> = 1.9A
Q <sub>rr</sub>	Reverse Recovery Charge		63	94	nC	di/dt = 100A/µs ④
t <sub>on</sub>	Forward Turn-On Time	Intrinsic	Intrinsic turn-on time is negligible (turn-on is dominated by LS+LD)			

#### Notes:

- ${\rm \textcircled{O}}$  Repetitive rating; pulse width limited by max. junction temperature. ( See fig. 11 )
- @ Starting  $T_J$  = 25°C, L = 25 mH,  $R_G$  = 25 $\Omega,\,I_{AS}$  = 3.1A. (See Figure 12)
- 3 I\_{SD}  $\leq$  1.9A, di/dt  $\leq$  270A/µs,  $V_{DD} \leq V_{(BR)DSS}, \, T_J \leq$  150°C
- ④ Pulse width  $\leq$  300µs; duty cycle  $\leq$  2%.
- $\ensuremath{\textcircled{}}$  When mounted on FR-4 board using minimum recommended footprint..
- $\ensuremath{\textcircled{}^{\circ}}$  When mounted on 1 inch square copper board, for comparison with other SMD devices.

### **Qualification Information<sup>†</sup>**

		Automotive (per AEC-Q101) <sup>††</sup>				
		qualification.	This part number(s) passed Automotive IR's Industrial and Consumer qualification ed by extension of the higher Automotive level.			
Moisture Sensi	Moisture Sensitivity Level		MSL1			
	Machine Model	Class M2(+/- 150V ) <sup>†††</sup> (per AEC-Q101-002)				
ESD	Human Body Model	Class H1A(+/- 500V ) <sup>†††</sup> (per AEC-Q101-001)				
	Charged Device Model	Class C5(+/- 2000V ) <sup>†††</sup> (per AEC-Q101-005)				
RoHS Compliant		Yes				

† Qualification standards can be found at International Rectifier's web site: http://www.irf.com/

the Exceptions (if any) to AEC-Q101 requirements are noted in the qualification report.

††† Highest passing voltage

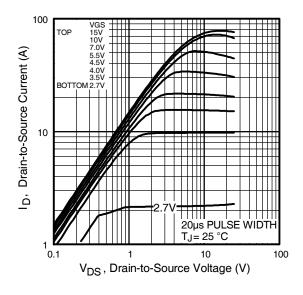


Fig 1. Typical Output Characteristics

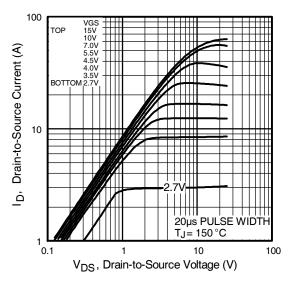


Fig 2. Typical Output Characteristics

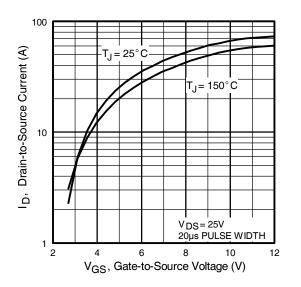


Fig 3. Typical Transfer Characteristics

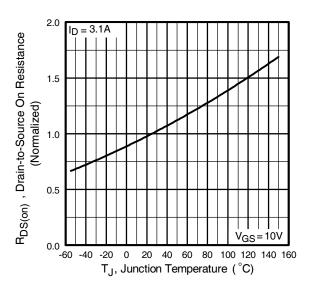


Fig 4. Normalized On-Resistance Vs. Temperature

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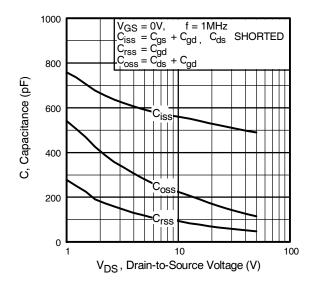


Fig 5. Typical Capacitance Vs. Drain-to-Source Voltage

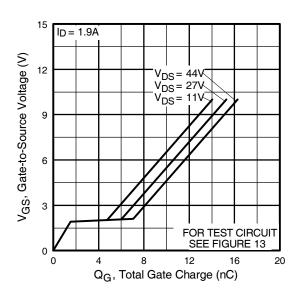


Fig 6. Typical Gate Charge Vs. Gate-to-Source Voltage

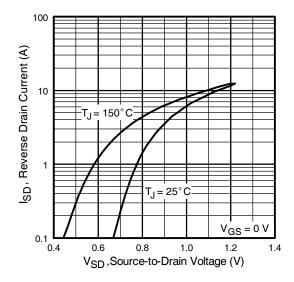


Fig 7. Typical Source-Drain Diode Forward Voltage

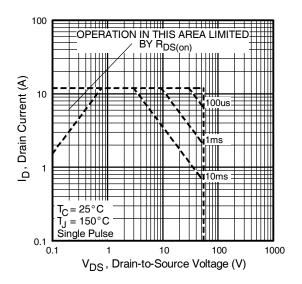
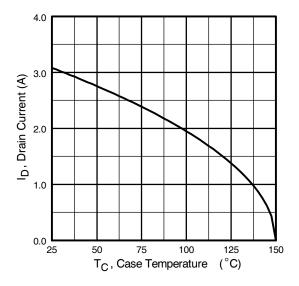
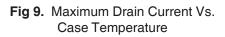
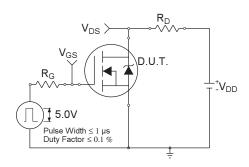


Fig 8. Maximum Safe Operating Area

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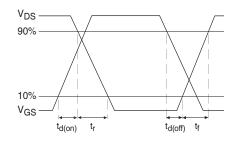


Fig 10b. Switching Time Waveforms

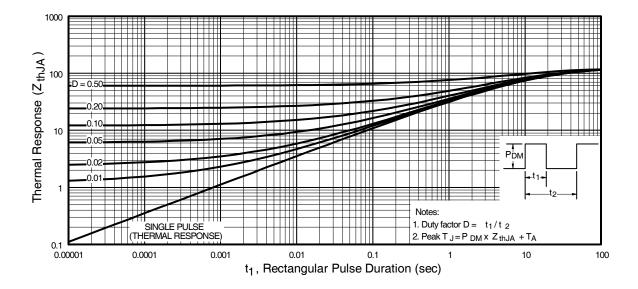


Fig 11. Maximum Effective Transient Thermal Impedance, Junction-to-Ambient

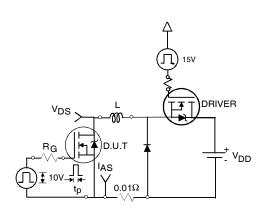


Fig 12a. Unclamped Inductive Test Circuit

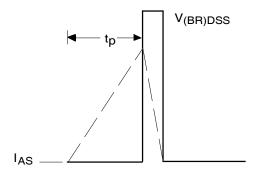


Fig 12b. Unclamped Inductive Waveforms

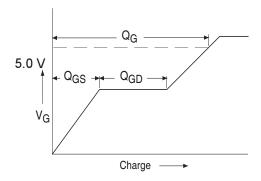
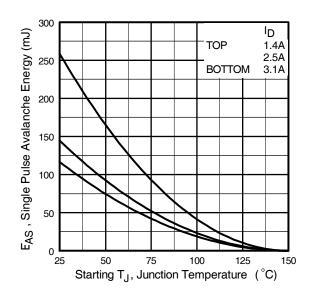
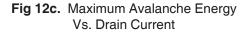


Fig 13a. Basic Gate Charge Waveform





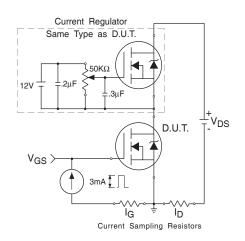
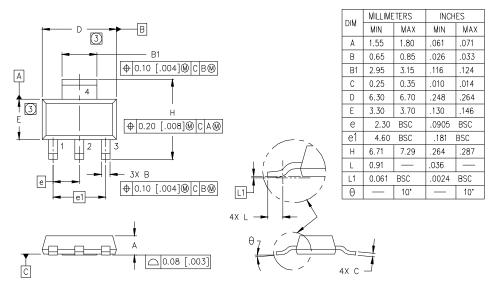


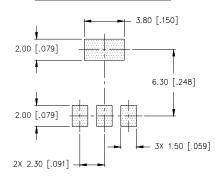
Fig 13b. Gate Charge Test Circuit

### SOT-223 (TO-261AA) Package Outline

Dimensions are shown in milimeters (inches)



MINIMUM RECOMMENDED FOOTPRINT



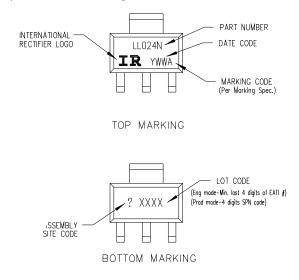
LEAD ASSIGNMENTS

- 1 = GATE 2 = DRAIN
- 3 = SOURCE
- 4 = DRAIN

NOTES:

- 1. DIMENSIONING & TOLERANCING PER ASME Y14.5M-1994.
- 2. CONTROLLING DIMENSION: INCH.
- DIMENSIONS DO NOT INCLUDE MOLD FLASH,
  OUTLINE CONFORMS TO JEDEC OUTLINE TO-261AA.
- OUTLINE CONFORMS TO JEDEC OUTLINE TO-261AA.
  DIMENSIONS ARE SHOWN IN MILLIMETERS [INCHES].

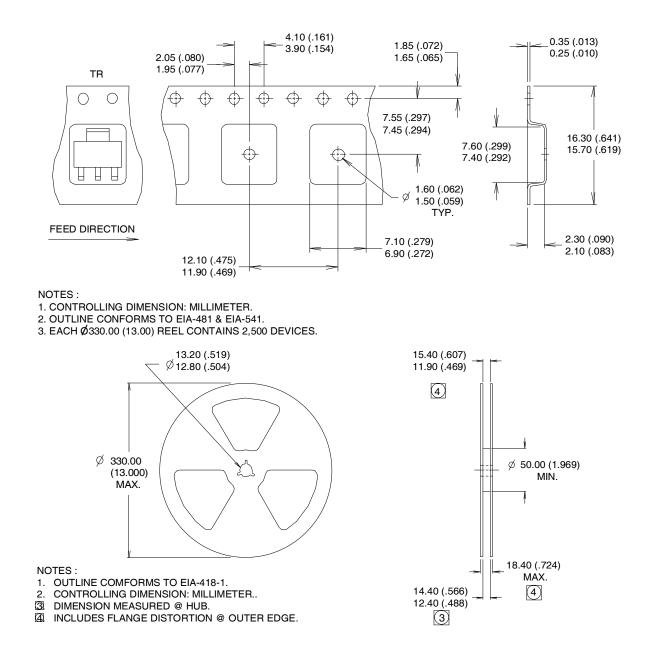
### SOT-223 (TO-261AA) Part Marking Information



Note: For the most current drawing please refer to IR website at http://www.irf.com/package/

### SOT-223 (TO-261AA) Tape & Reel Information

Dimensions are shown in milimeters (inches)





## **Ordering Information**

Base part	Package Type	Standard Pack		Complete Part Number
		Form	Quantity	
AUIRLL024N	SOT-223	Tube	95	AUIRLL024N
		Tape and Reel	2500	AUIRLL024NTR

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#### WORLD HEADQUARTERS:

101 N. Sepulveda Blvd., El Segundo, California 90245

Tel: (310) 252-7105